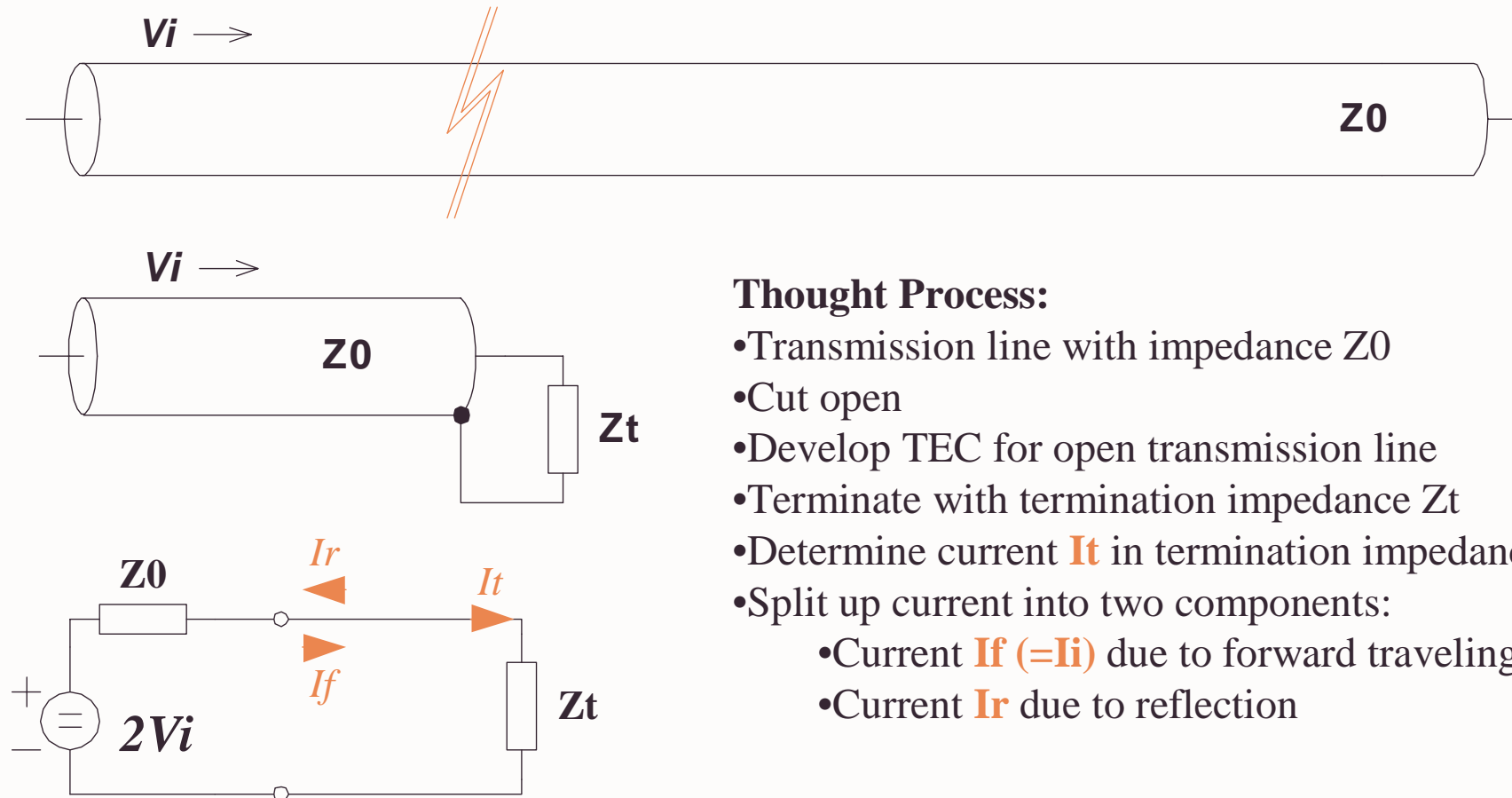


TL/Finite Length

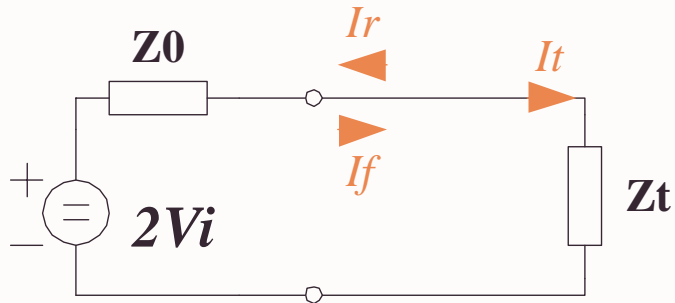
What happens when a traveling wave reaches the end of a transmission line?



Thought Process:

- Transmission line with impedance Z_0
- Cut open
- Develop TEC for open transmission line
- Terminate with termination impedance Z_t
- Determine current I_t in termination impedance
- Split up current into two components:
 - Current $I_f (=I_i)$ due to forward traveling wave
 - Current I_r due to reflection

TL/Finite Length/Reflection Coefficient



$$I_t = \frac{2V_i}{Z_0 + Z_t} \quad I_f = \frac{V_i}{Z_0} = I_i$$

$$I_r = I_f - I_t = \frac{V_i}{Z_0} - \frac{2V_i}{Z_0 + Z_t}$$

$$I_r = \frac{V_i}{Z_0} \cdot \frac{Z_t - Z_0}{Z_t + Z_0}$$

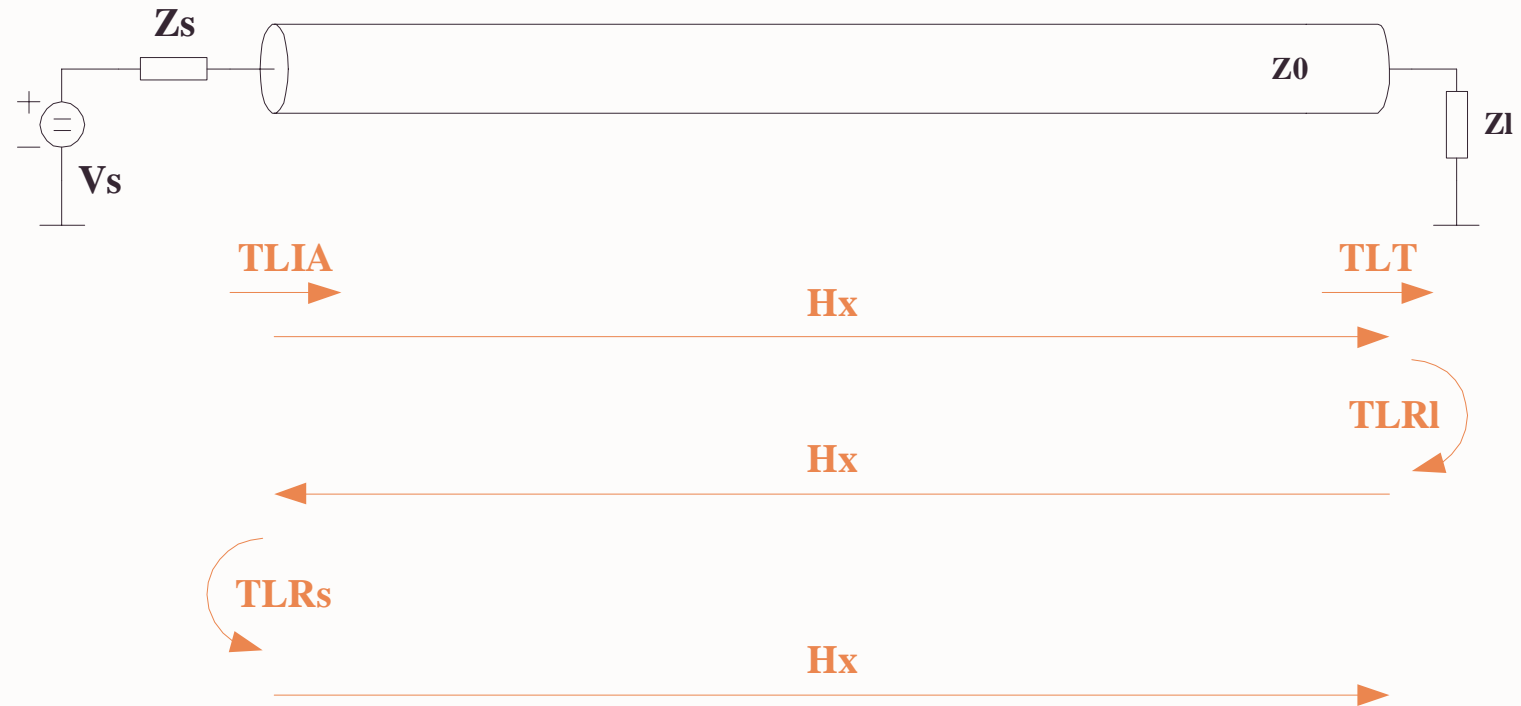
Termination current is the superposition of the current due to the forward traveling wave, and the current due to the reflection

Famous Telegrapher's Equation:

- Reflection coefficient k_r
- k_r can be complex (and f-dependent)
- but in practice it is desirable to keep k_r constant and real

$$k_r = \frac{I_r}{I_i} = \frac{V_r}{V_i} = \frac{Z_t - Z_0}{Z_t + Z_0}$$

TL/Finite Length/TL/Coefficients



Definitions:

- $TLIA(p)$: TL Input Acceptance Coefficient
- $TLT(p)$: TL Output Transmission Coefficient
- $TLRl(p)$: TL Load-End Reflection Coefficient
- $TLRs(p)$: TL Source-End Reflection Coefficient

TL/Finite Length/Coefficients/TLRl & TLRs

Load-end reflection coefficient TLRl(p):

$$TLRl(p) = \frac{Zl(p) - Z0(p)}{Zl(p) + Z0(p)}$$

Definition of reflection coefficient k_r applied to both load-end and source-end of transmission line...

Source-end reflection coefficient TLRs(p):

$$TLRs(p) = \frac{Zs(p) - Z0(p)}{Zs(p) + Z0(p)}$$

Reflection coefficients

- *No reflection* if $Z_t = Z_0$
- If Z_t and Z_0 are real:
 - k_r in a range $[-1..+1]$
- if $Z_t = 0 \rightarrow k_r = -1$
- if $Z_t = \infty \rightarrow k_r = +1$

TL/Finite Length/Coefficients/TLT

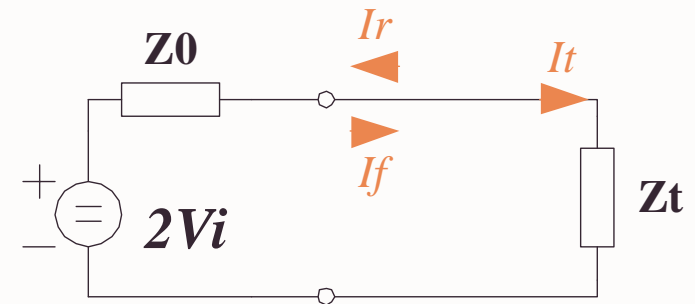
Output Transmission Coefficient $TLT(p)$:

$$TLT(p) = \frac{V_t}{V_i} = 1 + TLRl(p) \quad \text{because...}$$

$$1 + TLRl = 1 + \frac{Z_t - Z_0}{Z_t + Z_0} = \frac{Z_t + Z_0 + Z_t - Z_0}{Z_t + Z_0} = \frac{2Z_t}{Z_t + Z_0}$$

$$V_t = 2V_i \frac{Z_t}{Z_0 + Z_t}$$

$$V_t = V_i(1 + TLRl) \quad \text{q.e.d.}$$



TL/Finite Length/Coefficients/TLIA

Input acceptance coefficient TLIA(p):

$$TLIA(p) = \frac{Z_0(p)}{Z_s(p) + Z_0(p)}$$

*Fraction of the input voltage
accepted by the transmission
line...*

TL/Finite Length/Transfer Function

Transfer function $S_{\infty}(p)$ for signals emerging from the transmission line:



$$S_0(p) = TLIA(p) \cdot Hx(p) \cdot TLT(p)$$

$$S_1(p) = TLIA(p) \cdot Hx(p) (TLRI(p) \cdot Hx(p) \cdot TLRs(p) \cdot Hx(p)) TLT(p)$$

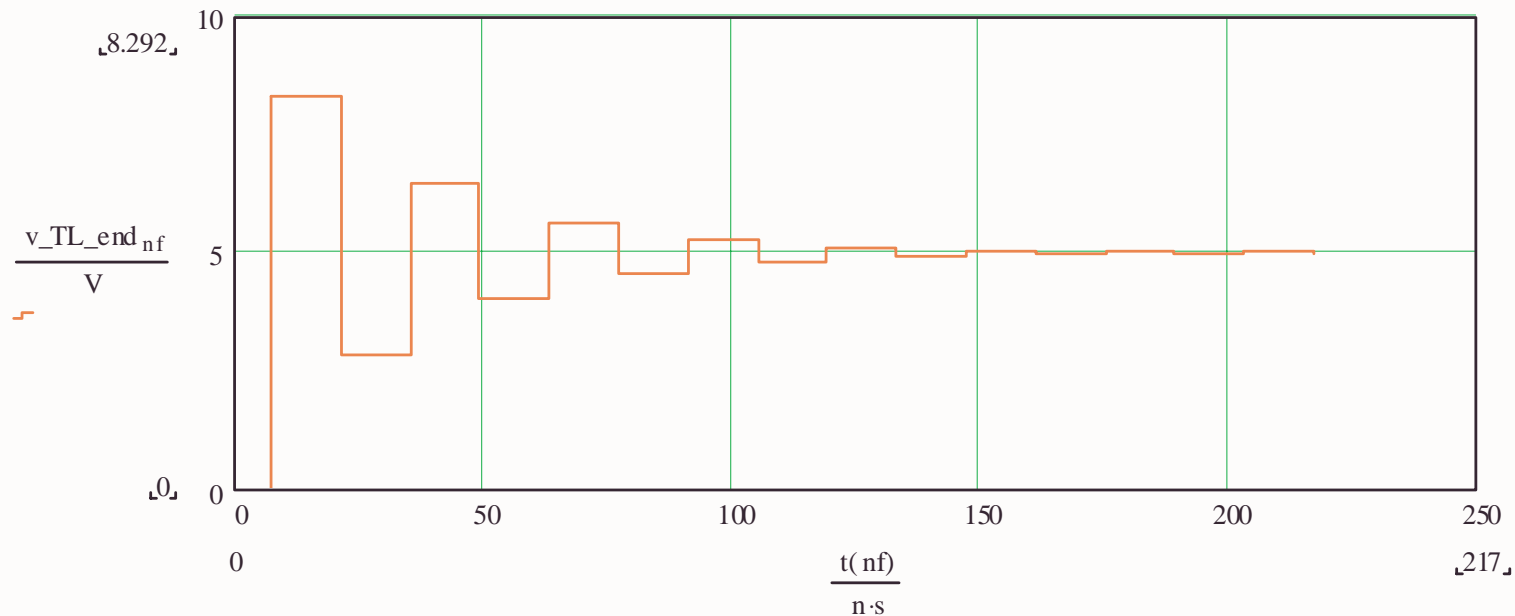
$$S_N(p) = TLIA(p) \cdot Hx(p) (TLRI(p) \cdot Hx(p)^2 \cdot TLRs(p))^N TLT(p)$$

$$S_{\infty}(p) = \sum_{N=0}^{\infty} S_N(p) = \frac{TLIA(p) \cdot Hx(p) \cdot (1 + TLRI(p))}{1 - TLRI(p) \cdot Hx(p)^2 \cdot TLRs(p)} = \frac{Vt(p)}{Vs(p)}$$

TL/Finite Length/Transfer Function/Example

Example: Reflections on a transmission line

- $C=140\text{pF/m}$, $L=350\text{nH/m}$. $R=G=\text{negligible}$. $\text{Length}=1\text{m}$.
- $Z_0=50\Omega$. $T_p_{\text{pul}}=7\text{ns/m}$.
- $V_{cc}=5\text{V}$. $Z_s=10\Omega$. $Z_l=10\text{k}\Omega$.
- $TLIA=0.833$. $TLR_l=0.99$. $TLR_s=-0.667$. $S_{\infty}=99.8\%$

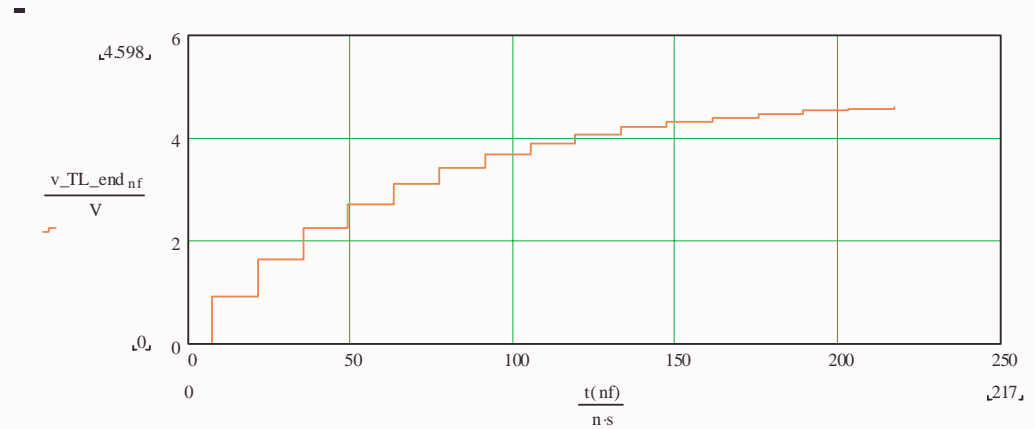


	0
0	1.658
1	-1.095
2	0.722
3	-0.477
4	0.315
5	-0.208
6	0.137
7	-0.09
8	0.06
9	-0.039
10	0.026
11	-0.017
12	0.011
13	-0.007
14	0.005
15	-0.003

$\frac{V}{V}$

Case 1: Low source impedance with unterminated transmission line

TL/Finite Length/Transfer Function/Example

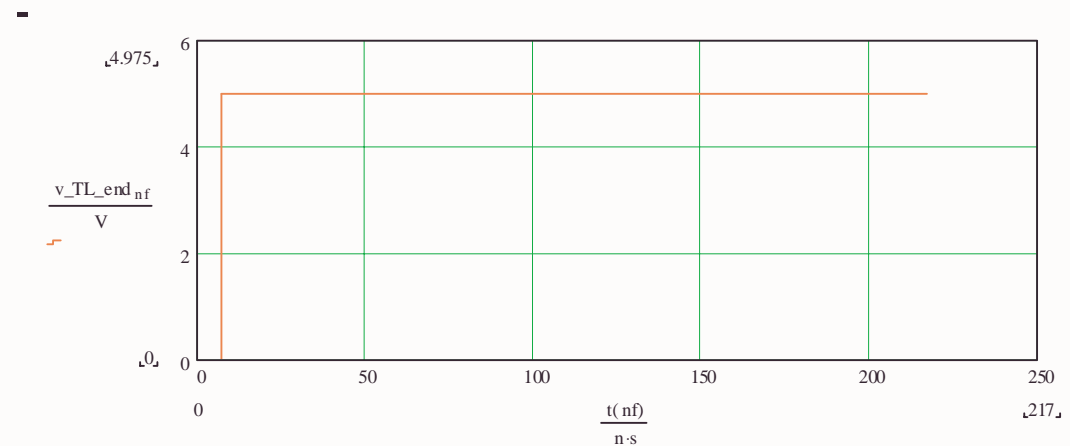


Case 2: High source impedance with unterminated transmission line

Same example... different termination resistors...

- top: $Z_s=500\Omega$. $Z_l=10k\Omega$.
($TLIA=0.091$. $TLR_l=0.99$. $TLR_s=0.818$.
 $S_\infty=92\%$)

- bottom: $Z_s=50\Omega$. $Z_l=10k\Omega$.
($TLIA=0.5$. $TLR_l=0.99$. $TLR_s=0$.
 $S_\infty=99.5\%$)



Case 3: Source-end terminated

TL Part 2/Overview

– Transmission Lines

- High Frequency Mechanisms in Transmission Lines
 - Skin-Effect
 - Proximity Effect
- Terminations
- Transmission Lines on PCBs
 - Equations

TL/Skin Effect

At low frequencies, current density inside a conductor is uniform. At high frequencies, it isn't.

Conductor carrying high frequency currents:

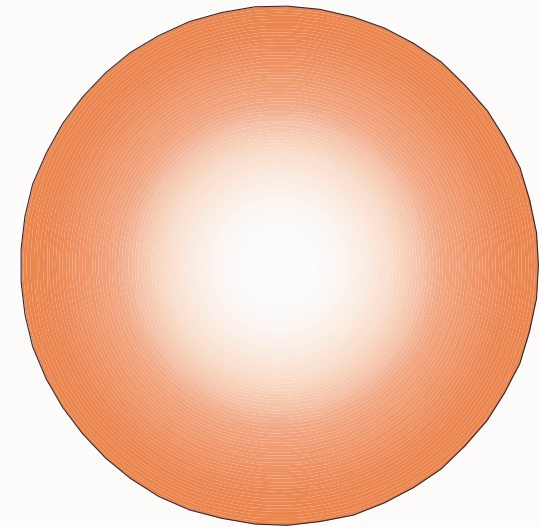
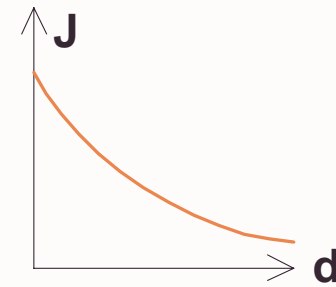
- Current flow primarily on the surface of a conductor
- Phenomena is called *skin effect*
- Current density falls off exponentially with depth into the conductor

$$J(d) = J_0 \cdot e^{-\frac{d}{\delta}}$$

with skin depth $\delta = \sqrt{\frac{\rho}{\pi \cdot f \cdot \mu}}$

ρ : material resistivity

μ : permeability



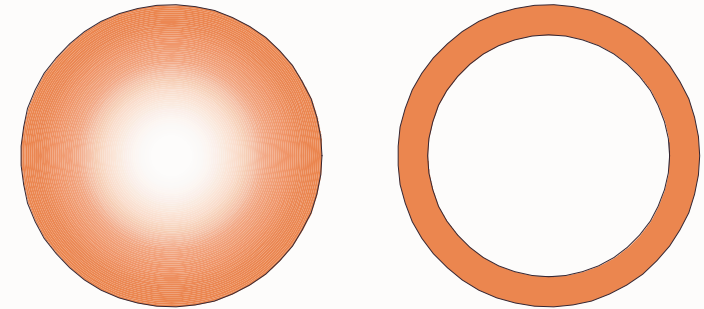
TL/Skin Effect

Skin effect

- Current density falls off exponentially with depth into the conductor
- Modelling: Current flows uniformly in an outer shell of the conductor with thickness δ .
- Skin depth is a material property (not a function of conductor shape)
- For most transmission lines, skin effect is the reason for their lossy nature

$$f_s = \frac{\rho}{\pi \mu r^2}$$

- for $f < f_s$ skin effect negligible. $R = R_{dc}$
- for $f > f_s$ skin effect. Resistance increases with square root of frequency



How to tackle skin effect problems

- Litz wire
- Planar conductors



TL/Skin Effect

conducting area:

$$A = r^2 \pi - (r - \delta)^2 \pi$$

$$A = \pi(2r\delta - \delta^2)$$

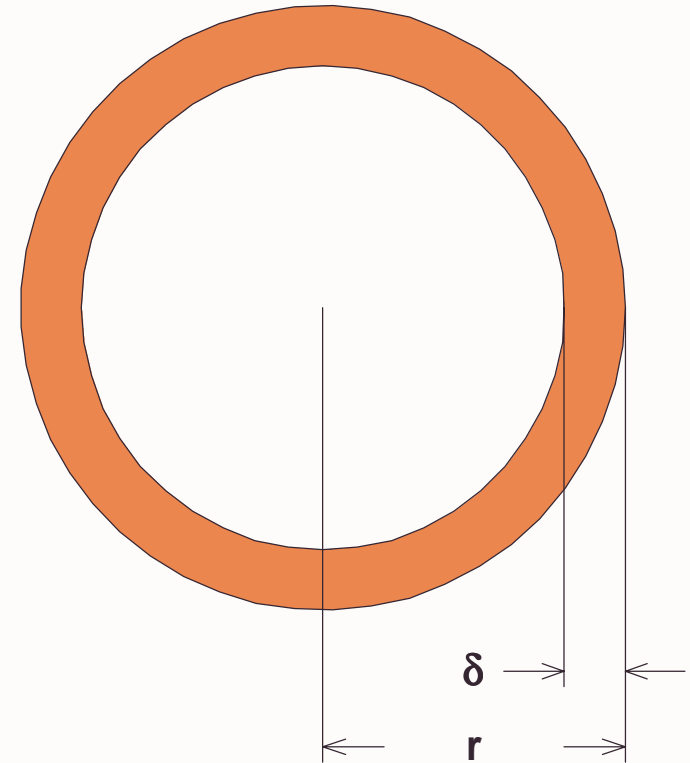
for high frequencies $\delta \ll r$:

$$A \approx \pi 2r\delta$$

Resistance (per unit length):

$$R_{pul} = \frac{\rho}{A}$$

$$R_{pul} = \frac{1}{2r} \sqrt{\frac{f\mu\rho}{\pi}}$$



TL/Skin Effect/Example

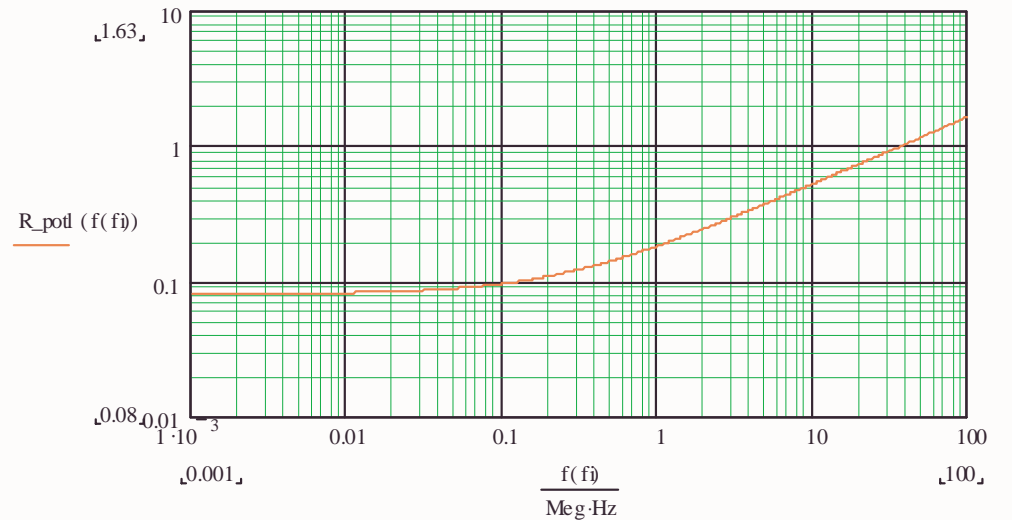
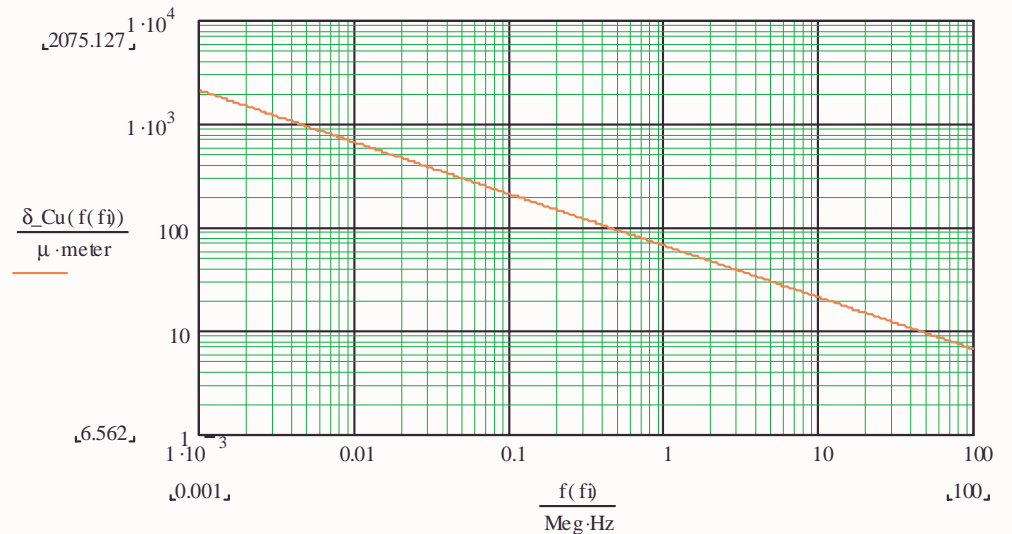
Example: AWG24 Transmission Line

- $C=40\text{pF/m}$, $L=400\text{nH/m}$, $R_{dc}=80\text{m}\Omega/\text{m}$
- wire radius AWG24: $r=253\mu\text{m}$
- skin effect frequency $f_s=67\text{kHz}$

Plots

- top right: skin depth
- bottom right: effective resistance per unit length

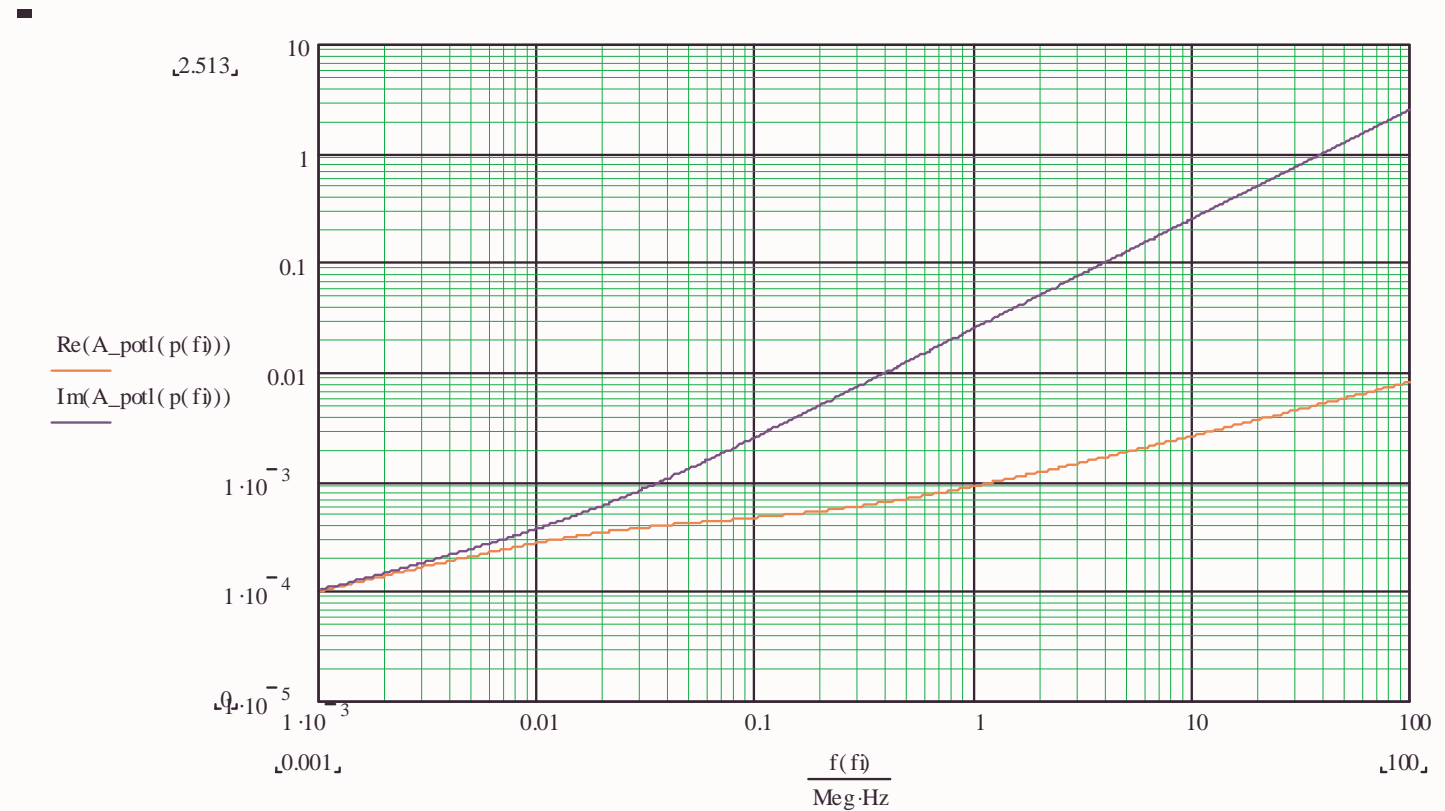
$$R_{pul} \approx \sqrt{R_{dc\ pul}^2 + R_h f_{pul}^2}$$



TL/Skin Effect/Propagation Constant A

Example: AWG24 Transmission Line. Three regions:

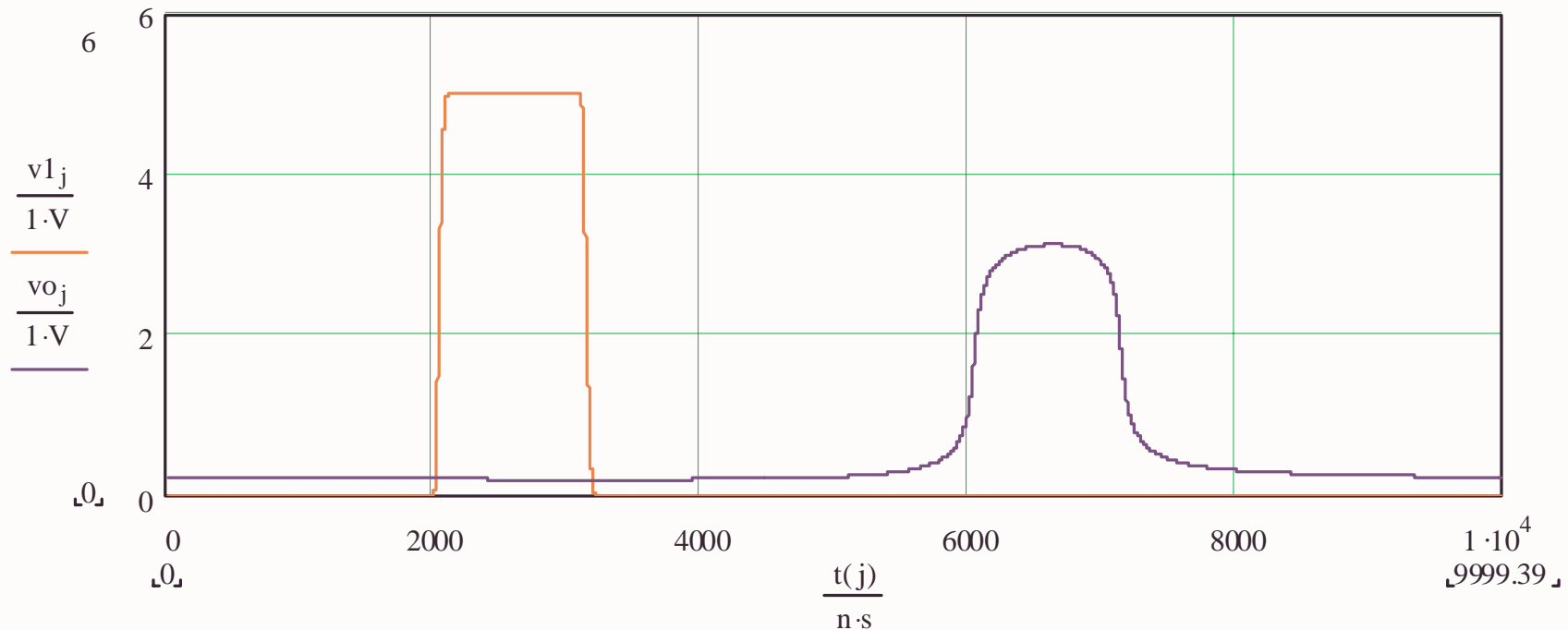
- Low frequency: RC TL behaviour (distortion)
- Mid frequency: LC TL behaviour (no distortion, just delay)
- High frequency: Distortion because of skin effect



TL/Skin Effect/Example

Example: Transmission of a pulse over a long AWG24 Telephone Line

- $C=40\text{pF/m}$, $L=400\text{nH/m}$, $R=80\text{m}\Omega/\text{m}$
- $T_p=4\mu\text{s/km}$
- Length of transmission line: 1km

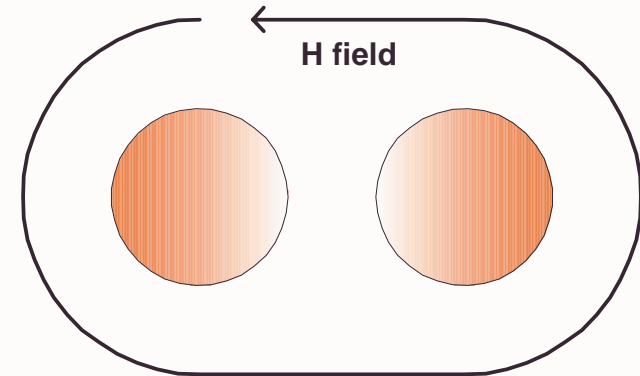


Signal distortion on an RLC Transmission Line due to skin effect

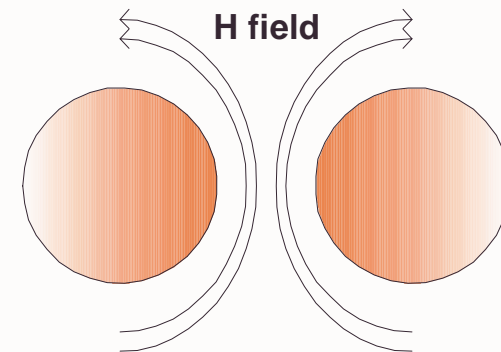
TL/Proximity Effect

Proximity Effect

- Current distribution in a conductor is affected by currents in adjacent conductors
- Like the skin effect, the proximity effect leads to a larger effective resistance at high frequencies
- Much harder to quantify... (use tables, graphs, field solvers)
- For same current direction increase in resistance is modest (even if conductors almost touch)
- For opposite current direction proximity effect can be many times higher than skin effect (depending on distance of conductors)
- Take proximity effect into account whenever conductors are brought closer together than about 3 times their diameter

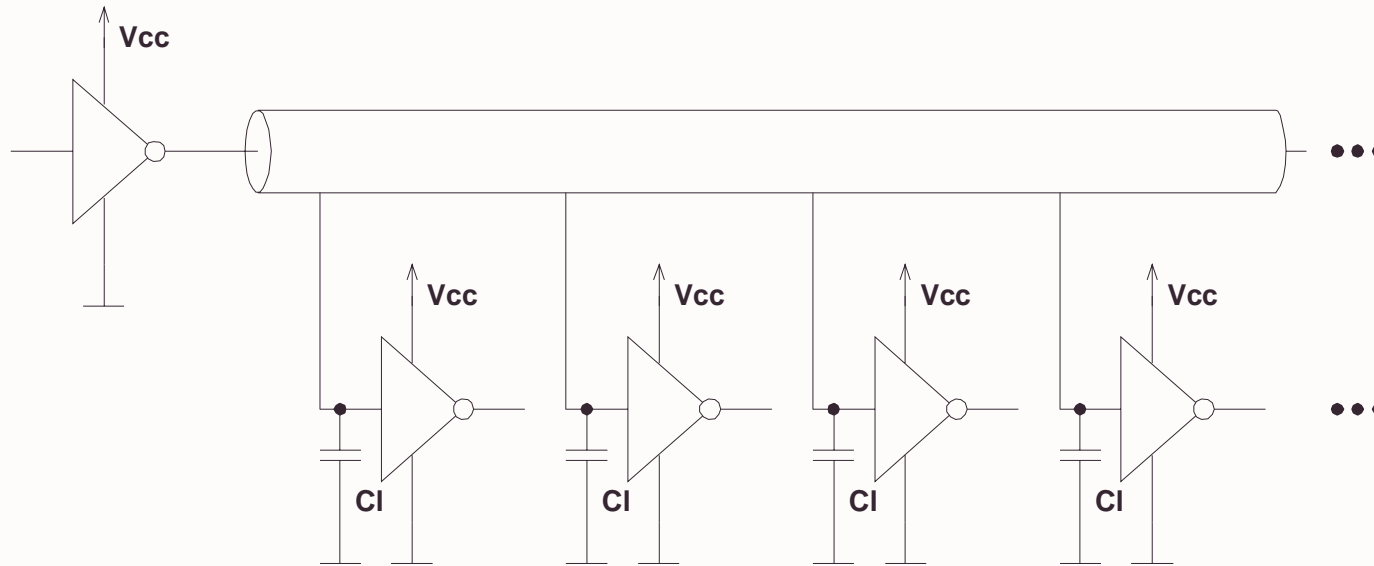


Same Current Direction



Opposite Current Direction

TL/Special Case



Equally Spaced Capacitive Loads

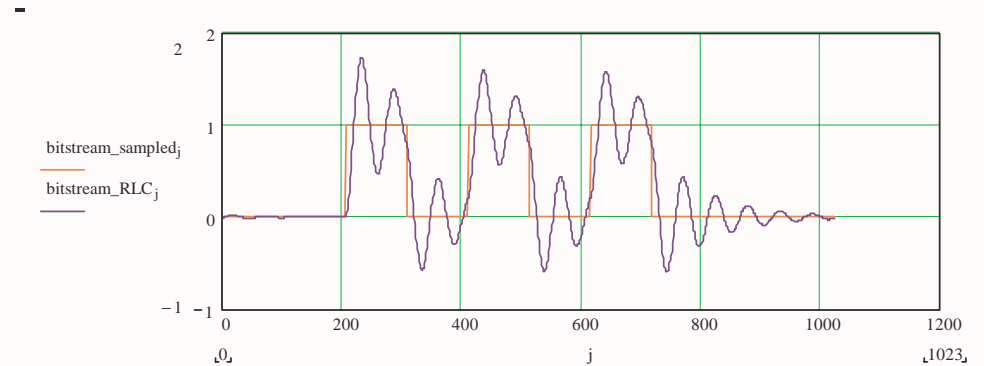
- Frequently encountered in large bus formations (e.g. memory modules)
- n capacitive loads are of equal value and spaced evenly over the length of the transmission line
- applicable if effective length of rising edge exceeds spacing between capacitive loads...

$$Z_0' = \sqrt{\frac{L}{C + \frac{n \cdot C_l}{length}}}$$

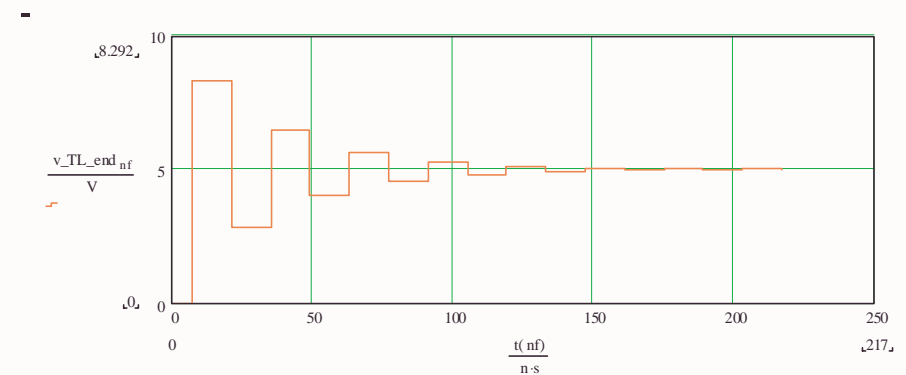
$$T_p' = \sqrt{L \left(C + \frac{n \cdot C_l}{length} \right)}$$

TL/Termination

- Short Lines ($l < \lambda/6$)
 - Termination required for damping



- Transmission Lines
 - Termination to eliminate reflections

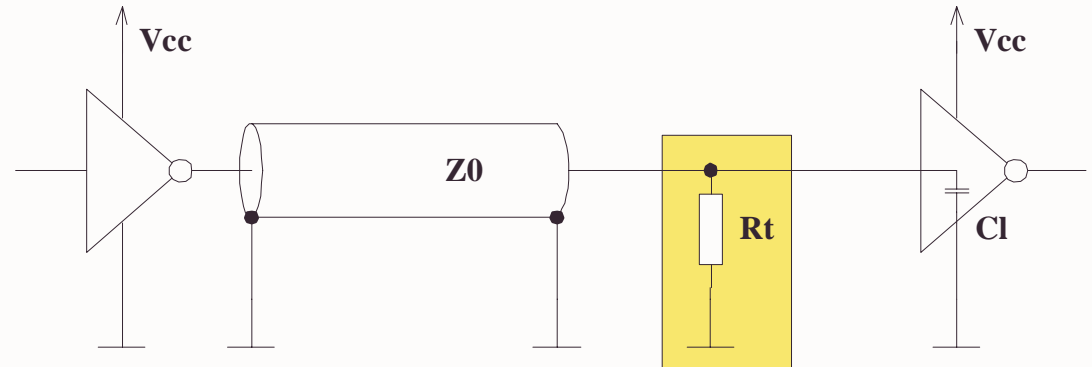


TL/Terminations/End Termination

End termination

- Driver connects directly to TL
- All reflections damped by termination resistor $R_t=Z_0$ ($TLR_l=0$)
- Received voltage is equal to the transmitted voltage ($S_\infty \approx 100\%$)
- Short rise time
- Drawbacks:
 - High power dissipation
 - Imbalanced load (difficult to drive)

$$T_{r_{TL_{end}}} = \sqrt{T_{r_{driver}}^2 + \left(\frac{2.2 \cdot Z_0 \cdot C_l}{2} \right)^2}$$



Assumptions:

- $R_t=Z_0$. $H_x \approx 1$. $TLIA \approx 1$. $TLR_l=0$.

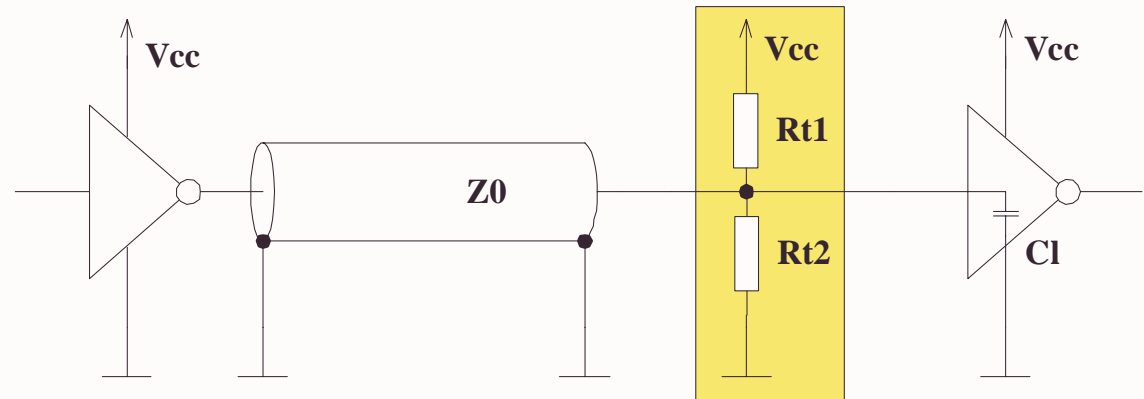
$$S_\infty(p) = \frac{TLIA(p) \cdot H_x(p) \cdot (1 + TLR_l(p))}{1 - TLR_l(p) \cdot H_x(p) \cdot TLR_s(p)}$$

$$S_\infty(p) = TLIA(p) \cdot H_x(p) \cdot (1 + TLR_l(p)) = 1$$

TL/Terminations/End Termination/Split

Split End termination

- $Z_0 = (R_{t1} \parallel R_{t2})$
- Advantages:
 - Balanced power dissipation
 - Easier to drive
- For CMOS, HCMOS...
 - $R_{t1} = R_{t2} = 2Z_0$



Assumptions:

- Signal is dc-balanced (equal 1's and 0')

$$Pd_{R_{t1}} = Pd_{R_{t2}} = \frac{V_{cc}^2}{4 \cdot Z_0}$$

$$Pd_{R_{t1}} + Pd_{R_{t2}} = \frac{V_{cc}^2}{2 \cdot Z_0}$$

Worst case: Static signal (1 or 0)...

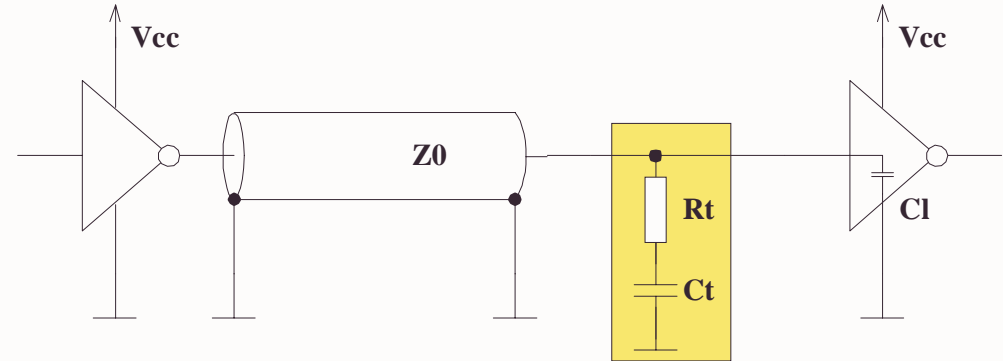
$$Pd_{R_{t1\max}} = Pd_{R_{t2\max}} = \frac{V_{cc}^2}{2 \cdot Z_0}$$

(assuming that resistance of TL is negligible)

TL/Terminations/End Termination/AC Biased

AC Biased End termination

- Time constant large vs signal period
- $R_t = Z_0$
- Advantages:
 - Lower average power consumption
 - Lower static power consumption
- Disadvantage
 - Difficult to drive if signal is not dc-balanced



Assumptions:

- Signal is dc-balanced (equal 1's and 0's)

$$Pd_{Rt1} = \frac{V_{cc}^2}{4 \cdot Z_0}$$

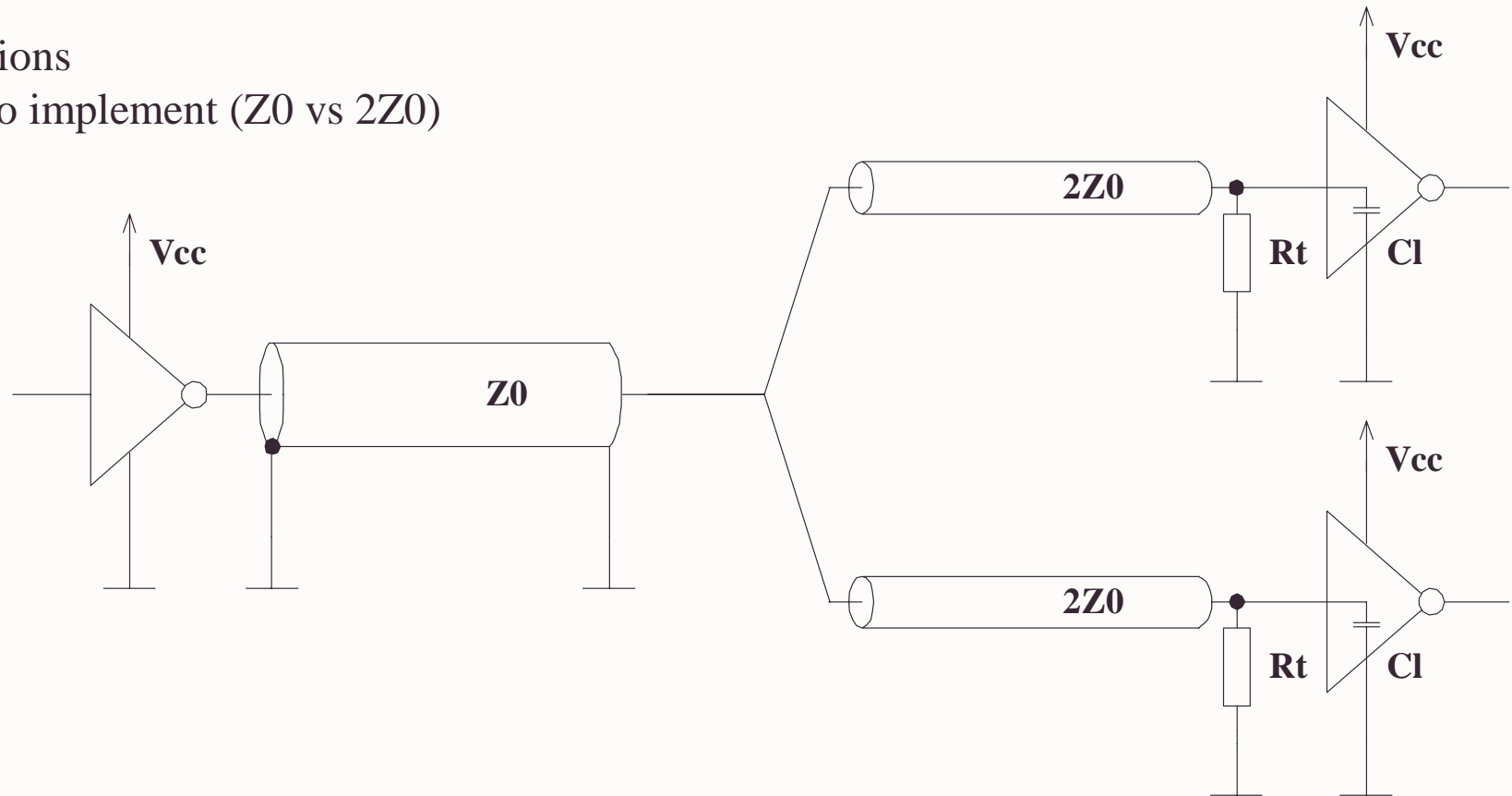
Static signal (1 or 0)...

$$Pd_{Rt1} = 0$$

TL/Terminations/End Termination/Bifurcation

Bifurcation

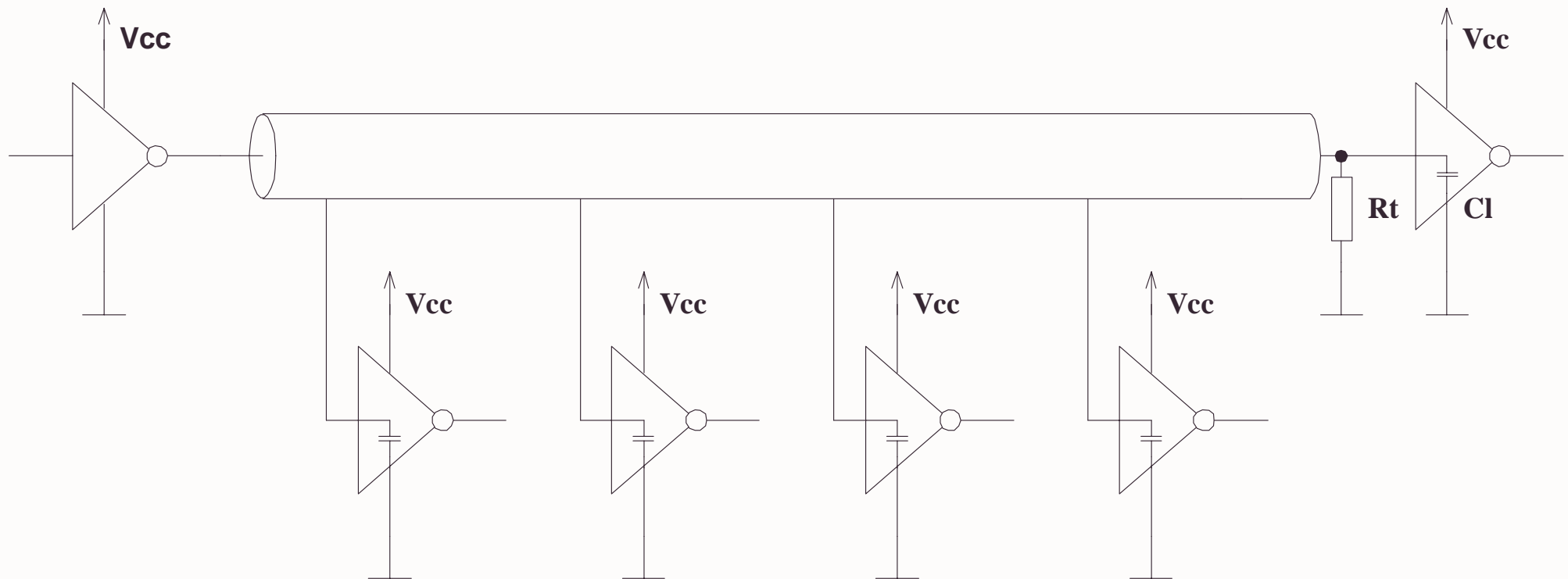
- $R_t = 2Z_0$
- No reflections
- Difficult to implement (Z_0 vs $2Z_0$)



TL/Terminations/End Termination/Daisy Chain

Daisy Chain Configuration

- Keep stubs as short as possible
- Minimise capacitive load
- Multiple stubs: Space equally



TL/Terminations/Source Termination

Source termination

- All reflections damped at the source side by source termination resistor $R_t=Z_0$ ($TLR_s=0$)

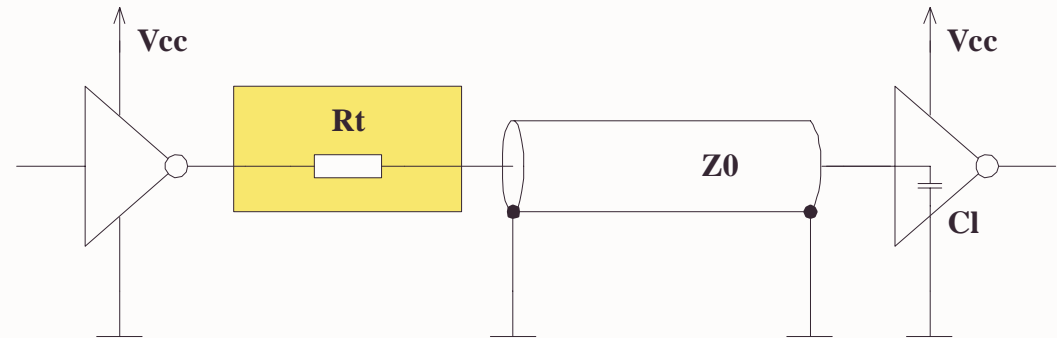
- Advantages:

- Lower average drive currents

- Disadvantages

- Output impedance of driver often not tightly specified

- Daisy-chaining not recommended



Assumptions:

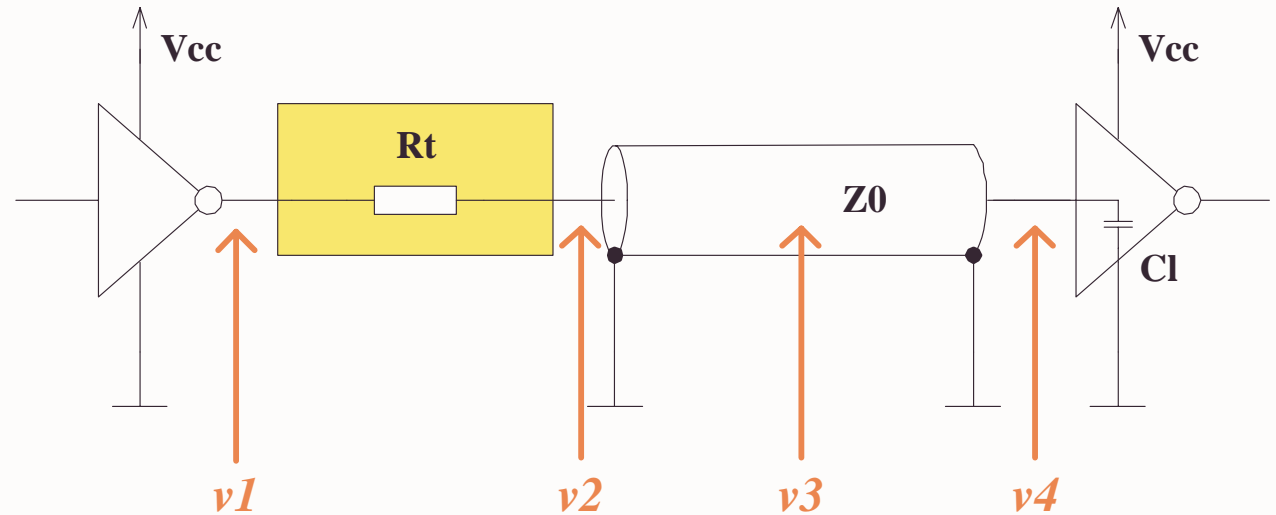
- $R_t=Z_0$. $H_x \approx 1$. $TLIA \approx 0.5$. $TLR_l=1$

$$S_{\infty}(p) = \frac{TLIA(p) \cdot H_x(p) \cdot (1 + TLR_l(p))}{1 - TLR_l(p) \cdot H_x(p) \cdot TLR_s(p)}$$

$$S_{\infty}(p) = TLIA(p) \cdot H_x(p) \cdot (1 + TLR_l(p)) = 1$$

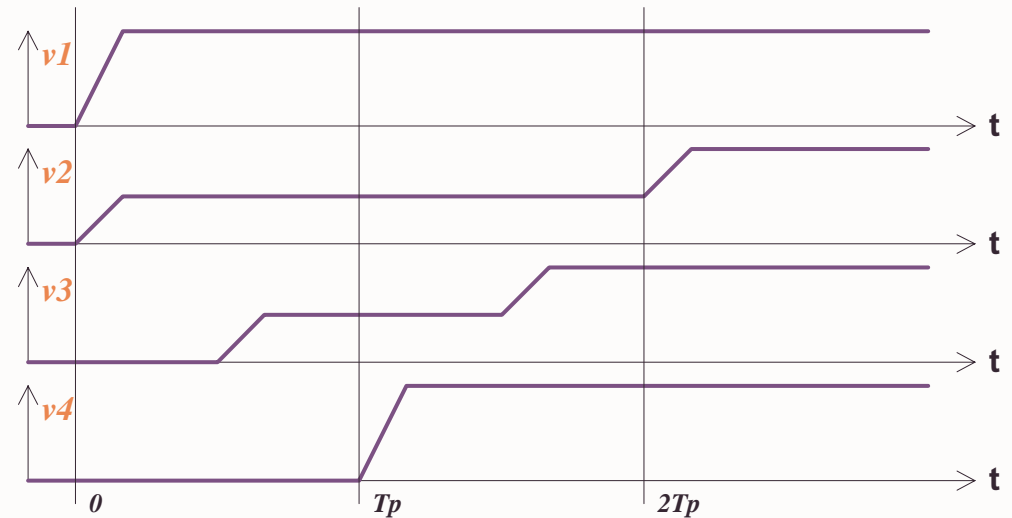
$$Tr_{TL_{end}} = \sqrt{Tr_{driver}^2 + (2.2 \cdot Z_0 \cdot Cl)^2}$$

TL/Terminations/Source Termination

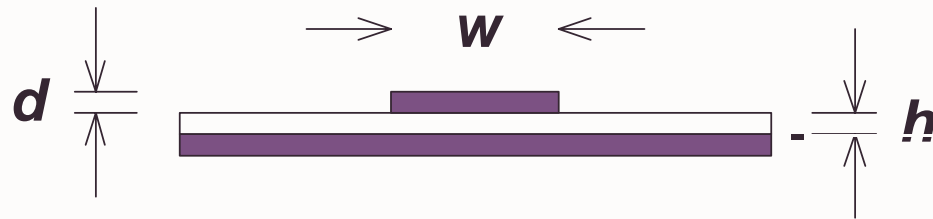


Source termination

- Driving signal cut in half ($TLIA=0.5$)
- Driving signal propagates down TL
- Reflection at load side ($TLR_l=1$)
- Reflected signal travels back
- Reflected signal damps out at the source termination ($TLR_s=0$)



TL/Terminations/Microstrip Equations



Example: Microstrip on FR4

- $\epsilon_r=4.5$. 2oz copper

Microstrip Equations

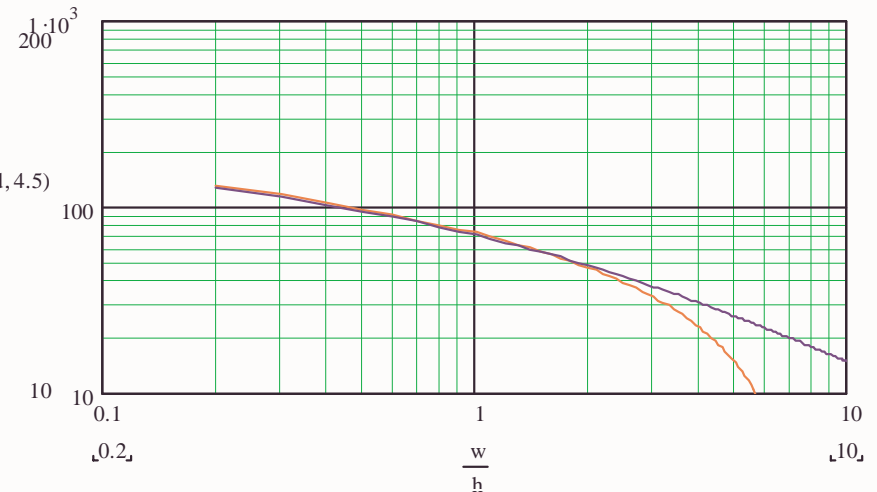
- Useful approximations
- Use numeric TL tools for improved accuracy

$$Z_0 \approx \frac{87\Omega}{\sqrt{\epsilon_r + 1.41}} \ln\left(\frac{5.98h}{0.8w + d}\right)$$

$$Tp_{pul} \approx 3.35 \frac{ns}{meter} \sqrt{0.475\epsilon_r + 0.67}$$

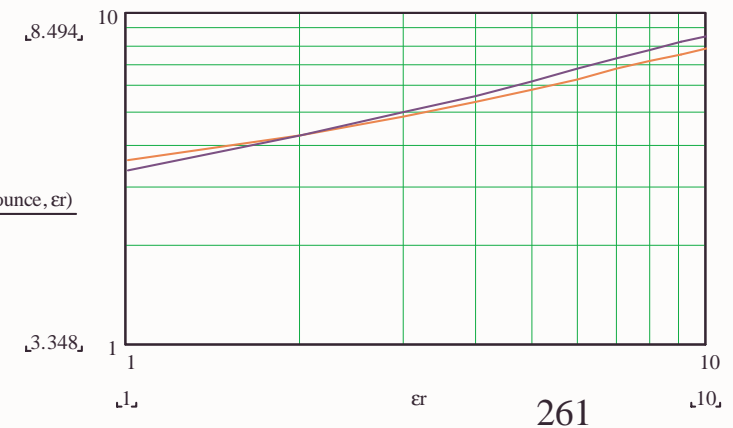
`Z0_microstrip_approx(h, w, d, 4.5)`

`Z0_microstrip(h, w, d, 4.5)`

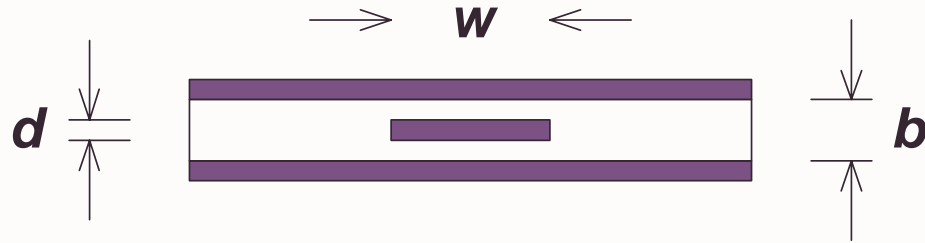


`Tp_microstrip_approx_pul(epsilon_r)`
 (pico-s / m-meter)

`Tp_microstrip_pul(0.005-inch, 0.01-inch, 2-ounce, epsilon_r)`
 (pico-s / m-meter)



TL/Terminations/Stripline Equations



Stripline Equations

- Useful approximations
- Use numeric TL tools for improved accuracy

$$Z_0 \approx \frac{60\Omega}{\sqrt{\epsilon_r}} \ln\left(\frac{1.9b}{0.8w + d}\right)$$

$$T_{p_{pul}} \approx 3.35 \frac{ns}{meter} \sqrt{\epsilon_r}$$